

E-MRS 2011 Fall Symposium K: Solution-Derived Electronic-Oxide Films, Nanostructures and Patterning, from Materials to Devices

**IOP Conference Series: Materials Science and Engineering
Volume 30**

**Warsaw, Poland
19 - 23 September 2011**

**ISBN: 978-1-63439-841-1
ISSN: 1779-8; 83**

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Accepted papers received: 16 January 2012

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